



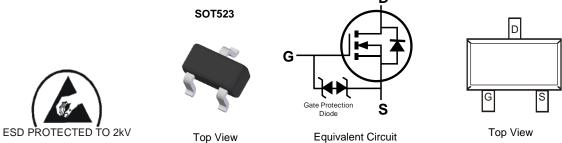
N-CHANNEL ENHANCEMENT MODE MOSFET

Features

- Low On-Resistance
- Very Low Gate Threshold Voltage
- Low Input Capacitance
- ESD Protected Gate to 2kV
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- **PPAP Capable (Note 4)**

Mechanical Data

- Case: SOT523
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Annealed over Alloy 42 Leadframe. Solderable per MIL-STD-202, Method 208 (8)
- Terminal Connections: See Diagram
- Weight: 0.002 grams (Approximate)



Ordering Information (Note 5)

Part Number	Qualification	Case	Packaging
DMN55D0UT -7	Commercial	SOT523	3,000/Tape & Reel
DMN55D0UTQ -7	Automotive	SOT523	3,000/Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

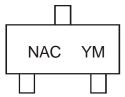
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q10x qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_compliance_definitions/.

5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



4

NAC = Product Type Marking Code YM = Date Code Marking Y = Year (ex: U = 2007)M = Month (ex: 9 = September)

Jul

7

2019

G

Aug

8

2020

Н

Sep

9

2021

Oct

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2022

J

Nov

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Date Code Key	,						
Year	2007		2015	2016	5 201	7 20)18
Code	U		С	D	E		F
Month	Jan	Feb	Mar	Apr	Мау	Jun	Ju

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Code

6

5

2023

Κ

Dec

D



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units
Drain-Source Voltage	V _{DSS}	50	V
Gate-Source Voltage	V _{GSS}	±12	V
Drain Current (Note 6) Continuous	ID	160	mA
Pulsed Drain Current (Note 6)	I _{DM}	560	mA

Thermal Characteristics

Characteristic	Symbol	Value	Units
Total Power Dissipation (Note 6)	PD	200	mW
Thermal Resistance, Junction to Ambient	R _{0JA}	625	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

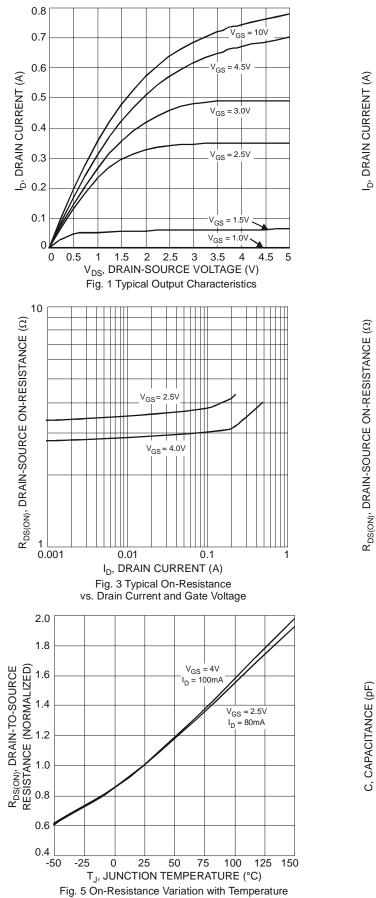
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

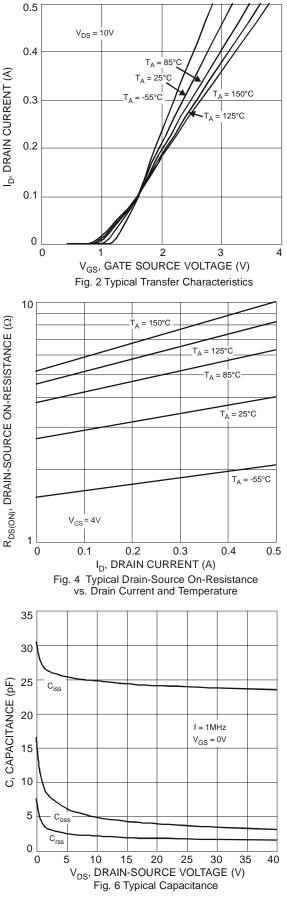
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	50	_		V	$V_{GS} = 0V, I_D = 250 \mu A$	
Zero Gate Voltage Drain Current	I _{DSS}			1	μA	$V_{DS} = 50V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}			1.0	uА	$V_{GS} = \pm 8V, V_{DS} = 0V$	
	1635			5.0	μ, ι	$V_{GS} = \pm 12V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(TH)}	0.7	0.8	1.0	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
Static Drain-Source On-Resistance	D		3.1	4	0	$V_{GS} = 4V, I_D = 100 mA$	
	R _{DS(ON)}		4	5	12	$V_{GS} = 2.5V, I_D = 80mA$	
Forward Transconductance	g fs	180		—	mS	V _{DS} = 10V, I _D = 100mA, f = 1.0KHz	
Diode Forward Voltage	V _{SD}	_	0.70	1.3	V	$V_{GS} = 0V, I_{S} = 100mA$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	CISS		25	—	pF		
Output Capacitance	Coss	_	5	—	рF	$V_{DS} = 10V, V_{GS} = 0V, f = 1.0MHz$	
Reverse Transfer Capacitance	C _{RSS}		2.1	—	pF		
Gate Resistance	R _G	_	500	—	Ω	$f = 1MHz$, $V_{GS} = 0V$, $V_{DS} = 0V$	
Total Gate Charge (V _{GS} = 4V)	Q_G	_	295	—	рС		
Total Gate Charge (V _{GS} = 8V)	Q_G		636	—	рС	V _{DS} = 10V,	
Gate-Source Charge	Q _{GS}		72	—	рС	I _D = 100mA	
Gate-Drain Charge	Q _{GD}		18	—	рС	1	
Turn-On Delay Time	t _{D(ON)}	_	6.0	—	ns		
Turn-On Rise Time	t _R		4.4	—	ns	$V_{DD} = 10V, V_{GS} = 4V,$	
Turn-Off Delay Time	t _{D(OFF)}	_	23.4	—	ns	$R_{G} = 25\Omega, I_{D} = 100mA$	
Turn-Off Fall Time	t _F	—	11.0	—	ns		

 Device mounted on FR-4 PCB, with minimum recommended pad layout.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing. Notes:

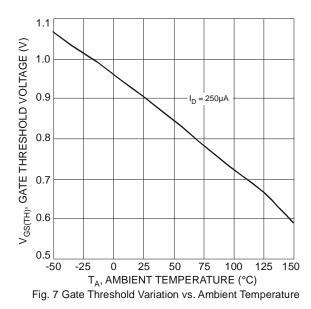
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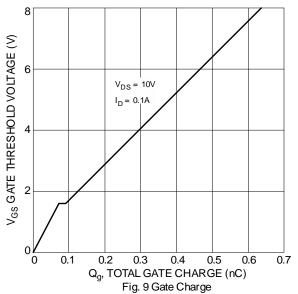


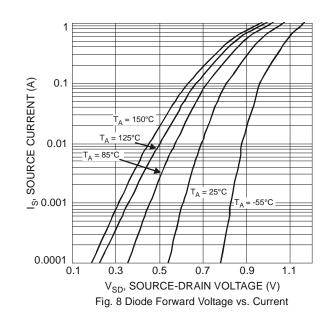




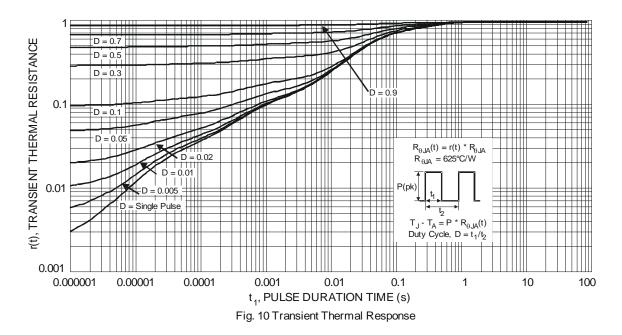








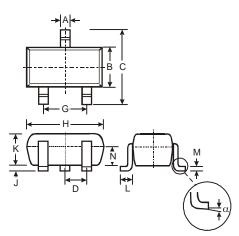






Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT523					
Dim	Min	Max	Тур		
Α	0.15	0.30	0.22		
В	0.75	0.85	0.80		
C	1.45	1.75	1.60		
D			0.50		
G	0.90	1.10	1.00		
Н	1.50	1.70	1.60		
J	0.00	0.10	0.05		
K	0.60	0.80	0.75		
L	0.10	0.30	0.22		
Μ	0.10	0.20	0.12		
N	0.45	0.65	0.50		
α	0°	8°			
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

Dimensions	Value (in mm)
Z	1.8
Х	0.4
Y	0.51
С	1.3
E	0.7

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SOT523



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